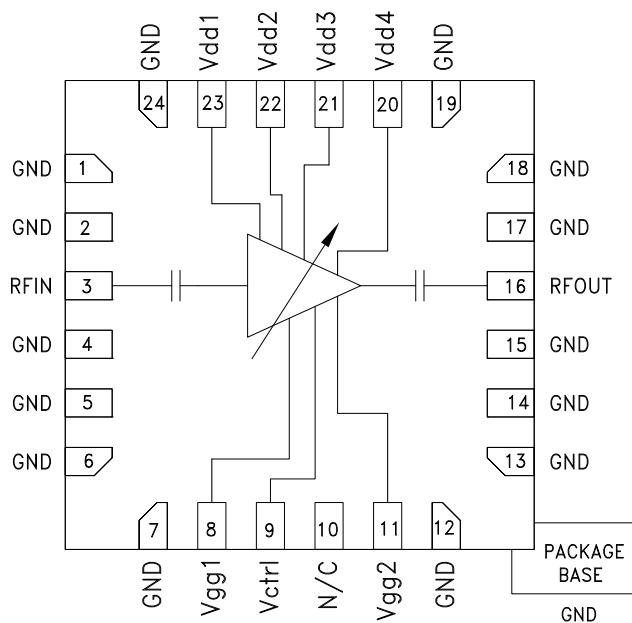



**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Typical Applications**

The HMC6187LP4E is ideal for:

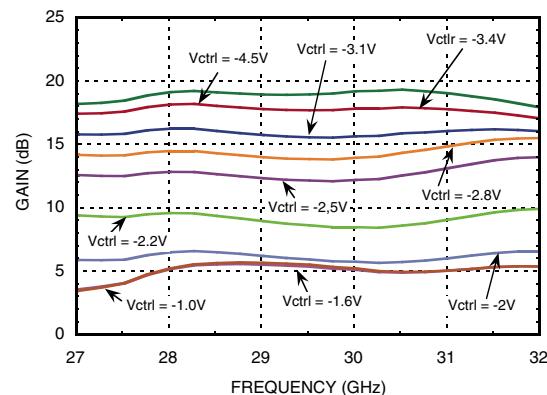
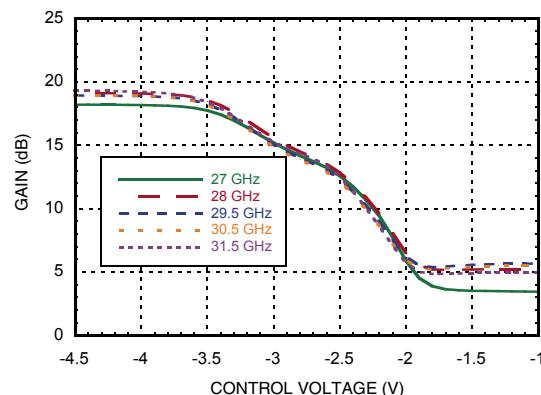
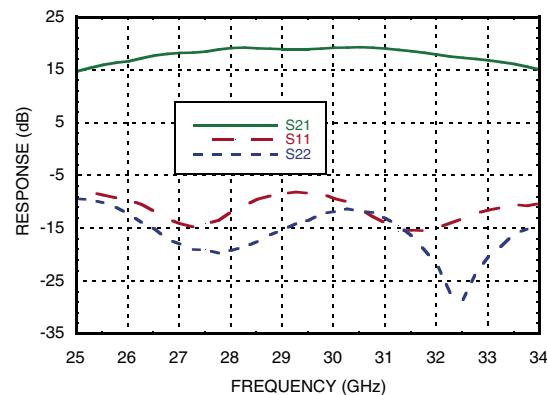
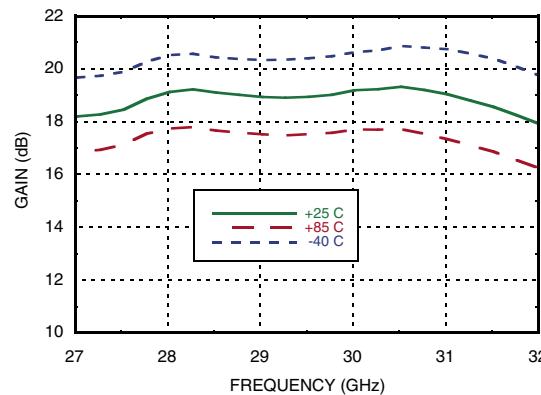
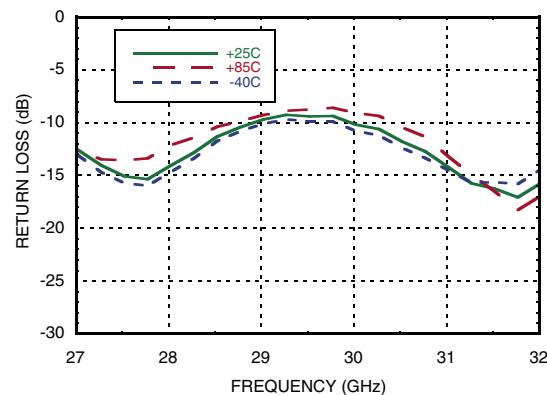
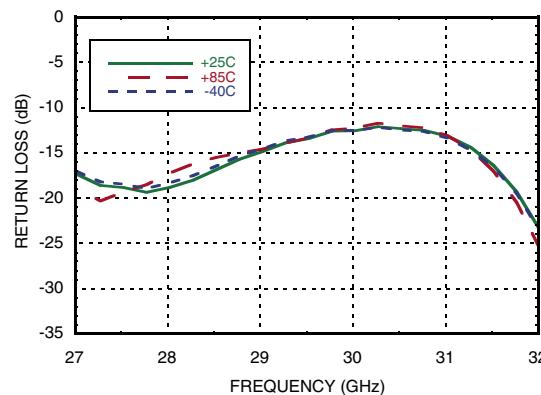
- Point-to-Point Radio
- Point-to-Multi-Point Radio
- EW & ECM Subsystems
- Ka-Band Radar & VSAT
- Test Equipment

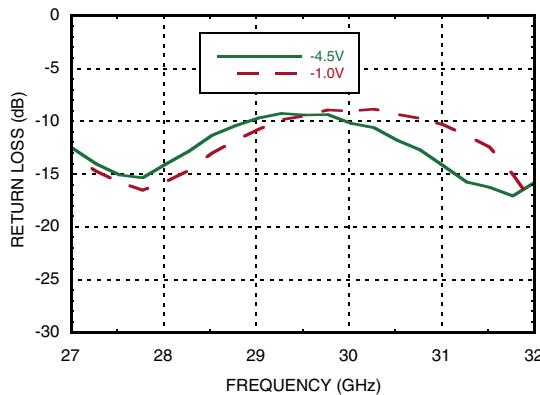
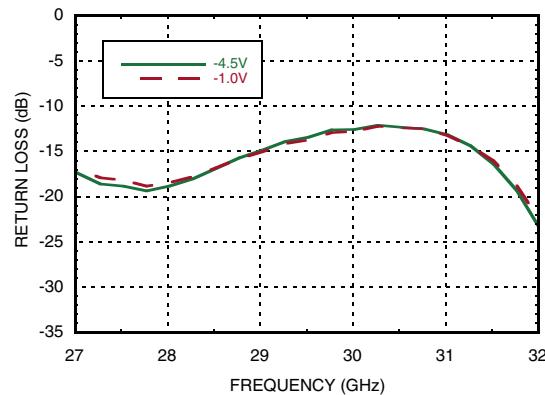
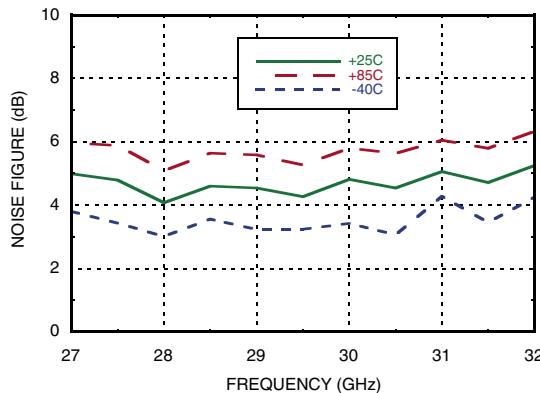
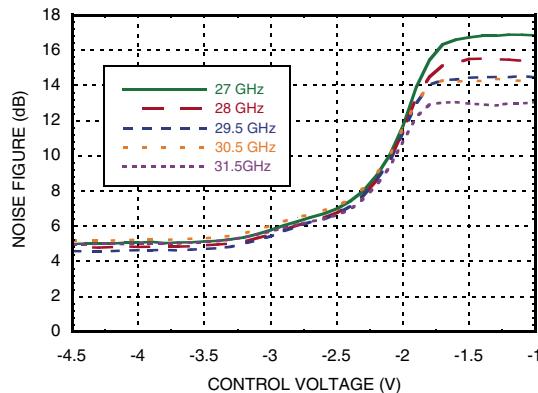
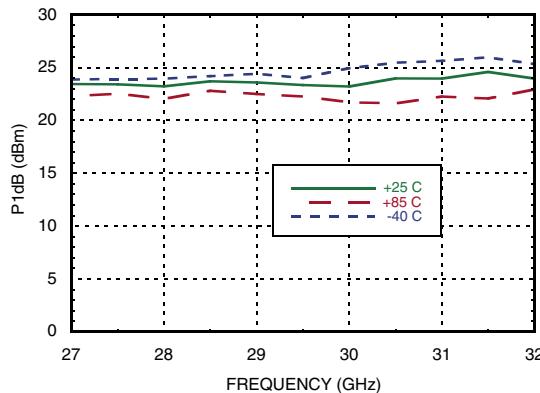
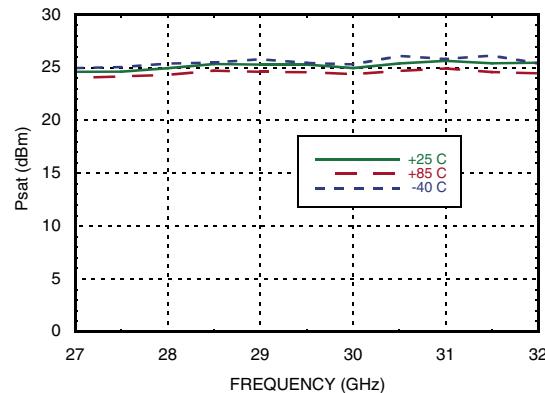
**Functional Diagram**

**Electrical Specifications,  $T_A = +25^\circ\text{C}$ ,  $Vdd1, 2, 3, 4 = 5\text{V}$ ,  $Vctrl = -4.5\text{V}$ ,  $Idd = 230\text{ mA}$ <sup>[1]</sup>**

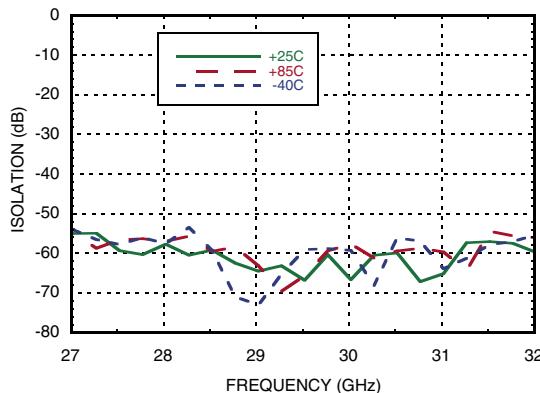
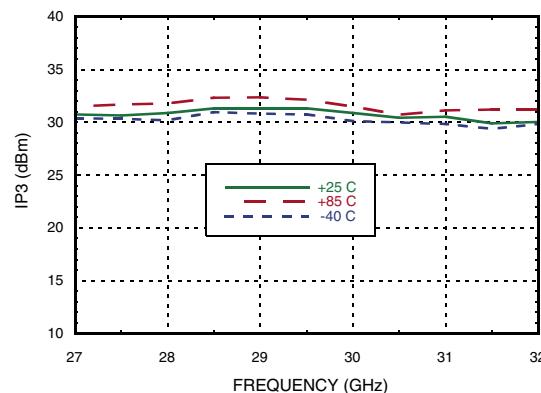
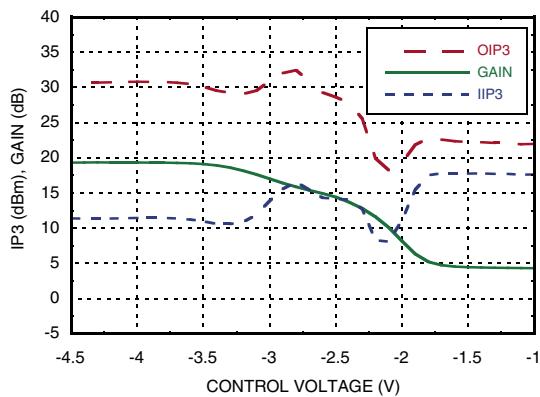
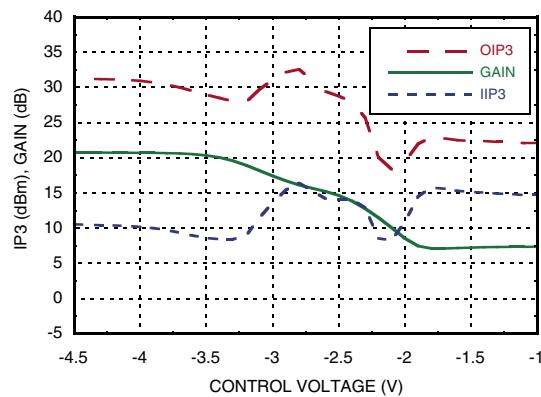
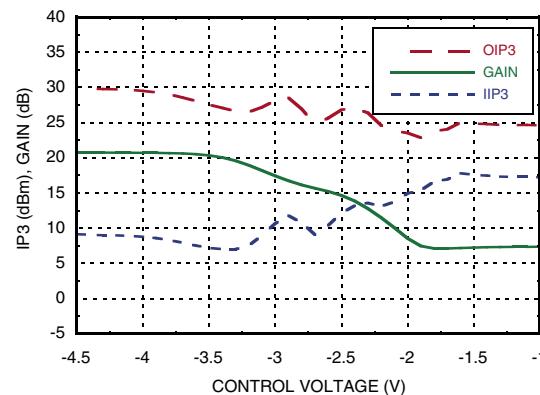
Parameter	Min.	Typ.	Max.	Units
Frequency Range		27 - 31.5		GHz
Gain <sup>[2]</sup>	16	19		dB
Gain Flatness		±0.5		dB
Gain Variation Over Temperature		0.02		dB/ °C
Gain Control Range		13		dB
Noise Figure <sup>[2]</sup>		4.5		dB
Input Return Loss		12		dB
Output Return Loss		15		dB
Output Power for 1 dB Compression (P1dB) <sup>[2]</sup>	21	24		dBm
Saturated Output Power (Psat) <sup>[2]</sup>		25		dBm
Output Third Order Intercept (IP3) <sup>[2]</sup>		31		dBm
Total Supply Current (Idd)		230		mA

<sup>[1]</sup> Set  $Vctrl = -4.5\text{V}$  and then adjust  $Vgg1, 2$  between  $-2\text{V}$  to  $0\text{V}$  to achieve  $Idd = 230\text{ mA}$  typical.

<sup>[2]</sup> Board loss subtracted out.


**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Gain vs. Control Voltage Range**

**Gain vs. Control Voltage**

**Broadband Gain & Return Loss**

**Gain vs. Temperature**

**Input Return Loss vs. Temperature**

**Output Return Loss vs. Temperature**



**Input Return Loss @  
Control Voltage Extreme**

**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Output Return Loss @  
Control Voltage Extreme**

**Noise Figure vs. Temperature**

**Noise Figure vs. Control Voltage**

**P1dB vs. Temperature, Vctrl= -4.5V**

**Psat vs. Temperature, Vctrl=-4.5V**


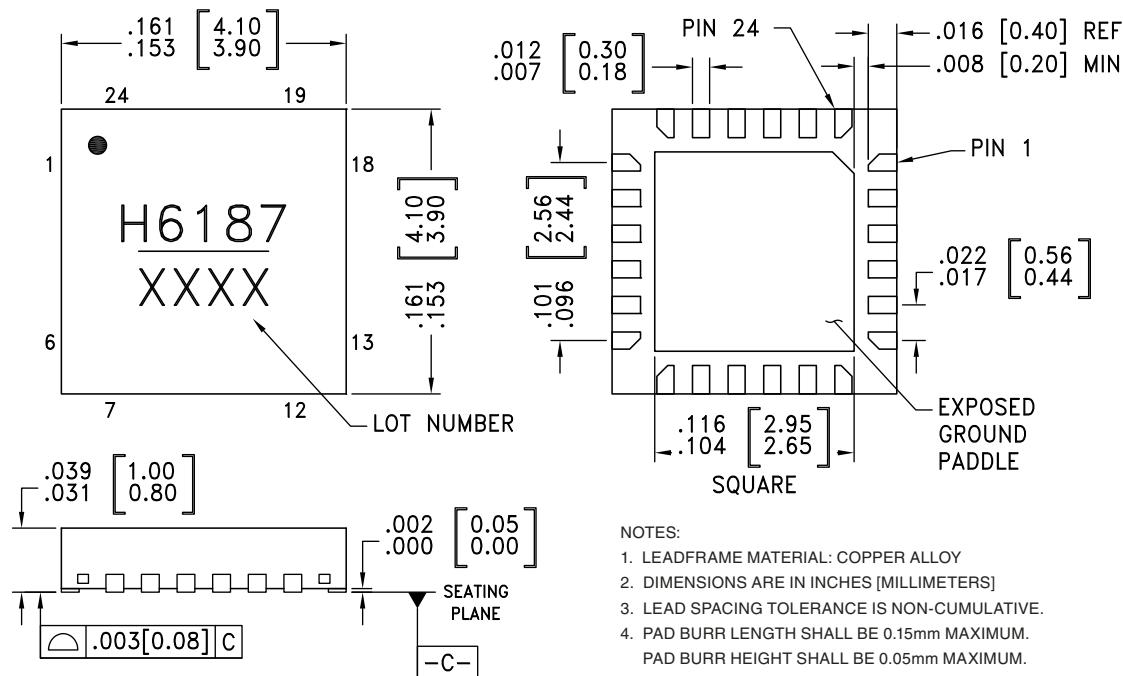
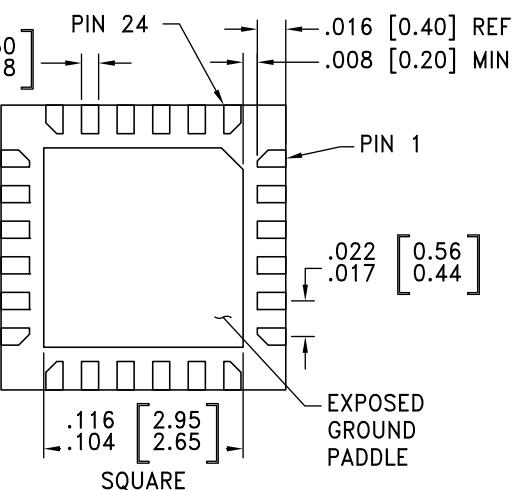

**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Reverse Isolation vs. Temperature**

**Output IP3 vs. Temperature, Vctrl=-4.5V**

**IP3 and Gain @ 27 GHz Pin = -7 dBm**

**IP3 and Gain @ 29.5 GHz Pin = -7 dBm**

**IP3 and Gain @ 31.5 GHz Pin = -7 dBm**



**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Absolute Maximum Ratings**

Drain Bias Voltage (Vdd1, 2, 3)	+5.5V
Gate Bias Voltage (Vgg1, 2)	-2.5 to 0V
Gain Control Voltage (Vctrl)	-5 to 0V
RF Power Input (RFIN)	+5 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85 °C) (derate 20.3 mW/°C above 85 °C) [1]	1.83 W
Thermal Resistance (Channel to ground paddle)	49.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0 Passed 100V

**Bias Voltage**

Vdd1,2,3 (V)	Idd Total (mA)
+5V	230
Vgg1,2 (V)	Igg Total (mA)
0V to -2V	<0.2 mA
Vctrl (V)	Ictrl (mA)
-4.5V to -1V	<1 mA


**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**
**Outline Drawing**

BOTTOM VIEW


## NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.  
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST  
BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR  
SUGGESTED LAND PATTERN.

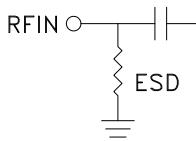
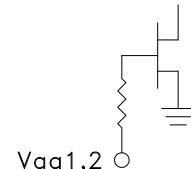
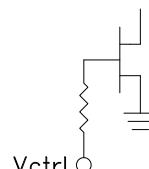
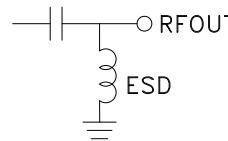
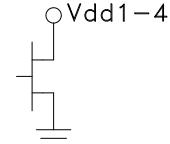
**Package Information**

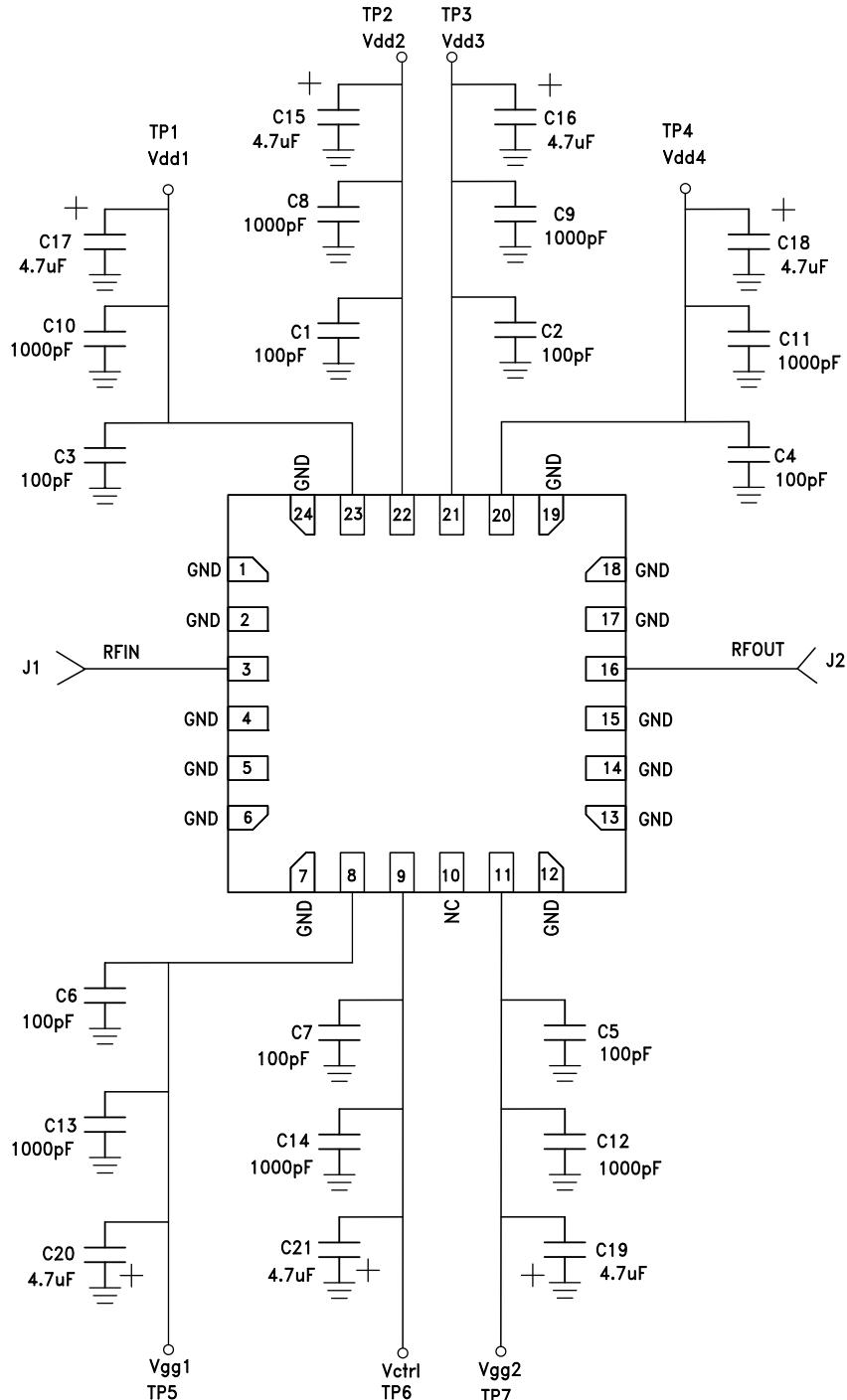
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC6187LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [1]	H6187 XXXX

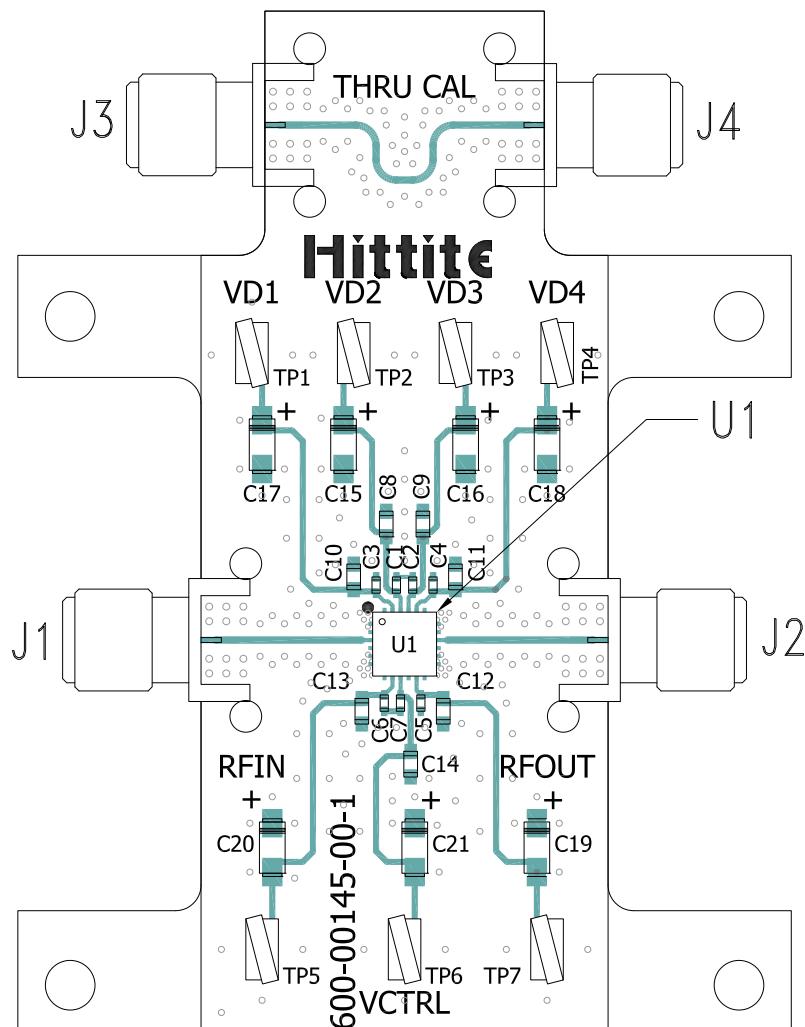
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX


**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 2, 4, 5, 6, 7, 12, 13, 14, 15, 17, 18, 19, 24	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
3	RFIN	This pin is AC coupled and matched to 50 Ohms.	
8, 11	Vgg1, 2	Adjust voltage to achieve typical Idd. Please follow "MMIC Amplifier Biasing Procedure" application note.	
9	Vctrl	Gain control Voltage for the amplifier. See assembly diagram for required external components.	
10	NC	The pins are not connected internally: however all data shown herein was measured with these pins connected to RF/DC ground externally.	
16	RFOUT	This pad is AC coupled and matched to 50 Ohms.	
20, 21, 22, 23	Vdd4, 3, 2, 1	Drain Bias Voltage for the amplifier. See assembly diagram for required external components	


**VARIABLE GAIN AMPLIFIER  
27 - 31.5 GHz**
**Application Circuit**



**Evaluation PCB**

**List of Materials for Evaluation PCB**
**EVAL01-HMC6187LP4E [1]**

Item	Description
J1 - J4	PCB Mount K Connectors
TP1 - TP7	DC Pin
C1 - C7	100 pF Capacitor, 0402 Pkg.
C8 - C14	10,000 pF Capacitor, 0603 Pkg.
C15 - C21	4.7 $\mu$ F Capacitor, CASE A
U1	HMC6187LP4E Variable Gain Amplifier
PCB [2]	600-00145-00 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.